

Application of

Applicants

: Howard E. Rhodes and Luan Tran

Serial No.

Filed

Title

: METHOD OF MAKING A SEMICONDUCTOR DEVICE HAVING

IMPROVED CONTACTS TO A THIN CONDUCTIVE LAYERS

Docket

: MIO 012 V2 (94-0112.4)

Assistant Commissioner for Patents Washington, DC 20231

Sir:

<u>INFORMATION DISCLOSURE STATEMENT</u> <u>UNDER 37 CFR §§ 1.56, 1.97, AND 1.98</u>

Applicants submit herewith patents, publications, and other information of which they are aware, which they believe may be material, as defined in 37 CFR §1.56(b), to the examination of this application and in respect of which there may be a duty to disclose in accordance with 37 CFR §1.56(a). While the information referred to in this Information Disclosure Statement may be material pursuant to 37 CFR §1.56(b), the filing of this Information Disclosure Statement is not intended to, pursuant to 37 CFR §1.97(h), constitute an admission that any patent, publication, or other information referred to is, or is considered to be, material to the patentability of this invention. Further, pursuant to 37 CFR §1.97(g), the filing of this Statement should not be construed as a statement that a search has been made or that no other material information exists.

A listing of all items of information cited is attached on PTO Form 1449. Copies of the items are enclosed for the convenience of the Examiner.

Attorney Docket No. - MIO 012 V2 (94-0112.4)

This Information Disclosure Statement is being filed within the period set forth in 37 CFR §1.97(b) because it accompanies the new patent application submitted herewith.

Respectfully submitted,

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By

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TWH/amm Encls.